

Features

- P-Channel, -5V Logic Level Control
- Very low on-resistance $R_{DS(on)}$ @ $V_{GS} = -4.5V$
- Fast Switching
- Enhancement mode
- 100% Avalanche Tested
- Pb-free lead plating; RoHS compliant

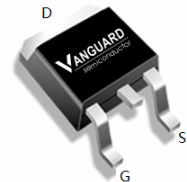


Halogen-Free

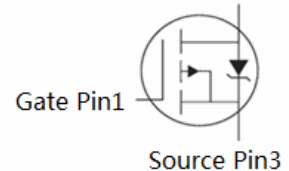
Part ID	Package Type	Marking	Tape and reel information
VSD007P06MS	TO-252	007P06M	2500pcs/reel

V_{DS}	-60	V
$R_{DS(on),TYP} @ V_{GS} = -10V$	9.0	mΩ
$R_{DS(on),TYP} @ V_{GS} = -4.5V$	11.0	mΩ
I_D	-80	A

TO-252



Drain Pin2



Maximum ratings, at $T_J = 25^\circ\text{C}$, unless otherwise specified

Symbol	Parameter		Rating	Unit
Common Ratings (Tc=25°C Unless Otherwise Noted)				
V _{GS}	Gate-Source Voltage		±20	V
V _{(BR)DSS}	Drain-Source Breakdown Voltage		-60	V
T _J	Maximum Junction Temperature		175	°C
T _{STG}	Storage Temperature Range①		-55 to 175	°C
I _S	Diode Continuous Forward Current	T _C =25°C	-80	A
Mounted on Large Heat Sink				
I _D	Continuous Drain current @V _{GS} =-10V	T _C =25°C	-80	A
		T _C =100°C	-51	A
I _{DM}	Pulse Drain Current Tested ②	T _C =25°C	-300	A
P _D	Maximum Power Dissipation	T _C =25°C	115	W
R _{θJC}	Thermal Resistance-Junction to Case		1.3	°C/W
R _{θJA}	Thermal Resistance Junction-Ambient		48	°C/W
Drain-Source Avalanche Ratings				
EAS	Avalanche Energy, Single Pulsed ③		56	mJ

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
Static Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =-250μA	-60	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current(Tc=25°C)	V _{DS} =-60V,V _{GS} =0V	--	--	-1	μA
	Zero Gate Voltage Drain Current(Tc=125°C)	V _{DS} =-60V,V _{GS} =0V	--	--	-100	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V,V _{DS} =0V	--	--	±100	nA
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} =V _{GS} ,I _D =-250μA	-1.0	-1.6	-2.5	V
R _{DS(ON)}	Drain-Source On-State Resistance ②	V _{GS} =-10V, I _D =-35A	--	9.0	12.0	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance ②	V _{GS} =-4.5V, I _D =-10A	--	11.0	15.0	mΩ
Dynamic Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
C _{iss}	Input Capacitance	V _{DS} =-30V,V _{GS} =0V, f=1MHz	--	6985	--	pF
C _{oss}	Output Capacitance		--	450	--	pF
C _{rss}	Reverse Transfer Capacitance		--	290	--	pF
R _g	Gate Resistance	f=1MHz		13.8		Ω
Q _g	Total Gate Charge	V _{DS} =-30V,I _D =-20A, V _{GS} =-10V	--	94	--	nC
Q _{gs}	Gate-Source Charge		--	21	--	nC
Q _{gd}	Gate-Drain Charge		--	25	--	nC
Switching Characteristics						
t _{d(on)}	Turn-on Delay Time	V _{DD} =-30V, I _D =-5A, R _G =6.8Ω, V _{GS} =-10V	--	19	--	nS
t _r	Turn-on Rise Time		--	26	--	nS
t _{d(off)}	Turn-Off Delay Time		--	89	--	nS
t _f	Turn-Off Fall Time		--	45	--	nS
Source- Drain Diode Characteristics@ T _J = 25°C (unless otherwise stated)						
V _{SD}	Forward on voltage	I _{SD} =-35A,V _{GS} =0V	--	-0.88	-1.3	V
t _{rr}	Reverse Recovery Time	T _J =25°C,I _{sd} =-20A, V _{GS} =0V	--	35	--	nS
Q _{rr}	Reverse Recovery Charge	di/dt=-500A/μs		175		nC

NOTE:

① Repetitive rating; pulse width limited by max. junction temperature.

② Pulse width ≤ 300μs; duty cycle ≤ 2%.

③ Limited by T_{Jmax}, starting T_J = 25°C, L = 0.5mH, R_G = 25Ω, I_{AS} = -15A, V_{GS} = -10V. Part not recommended for use above this value

Typical Characteristics

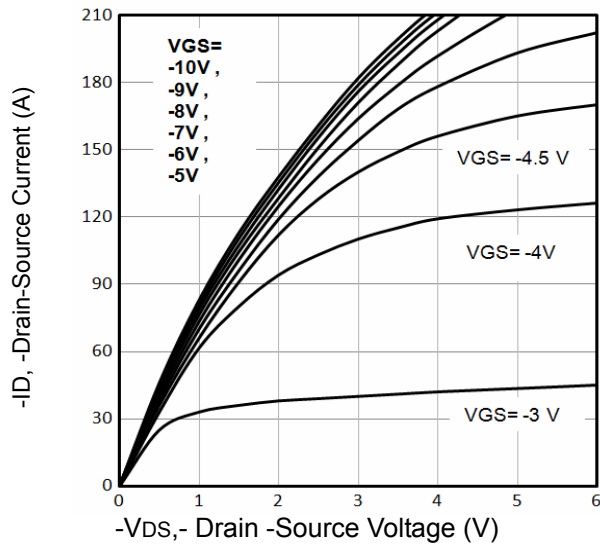


Fig1. Typical Output Characteristics

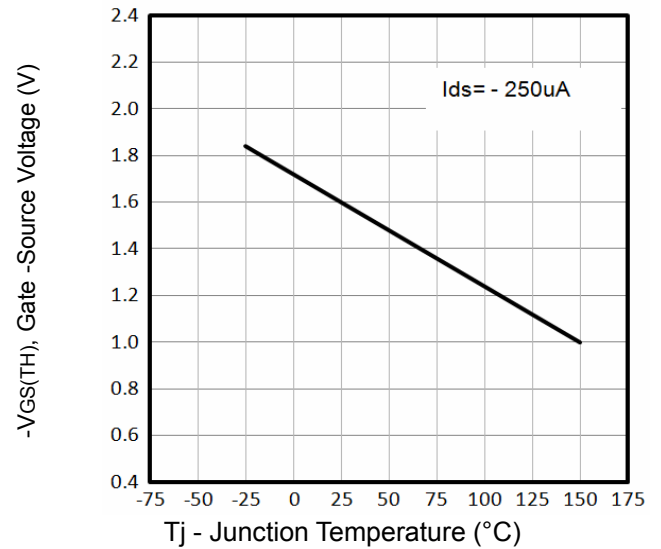


Fig2. Threshold Voltage Vs. Temperature

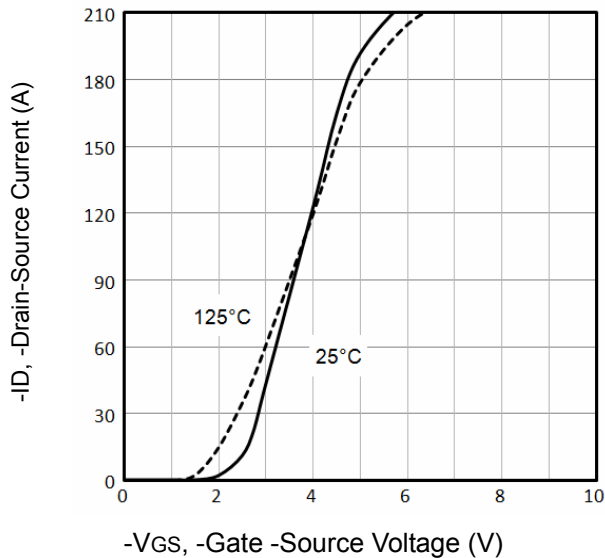


Fig3. Typical Transfer Characteristics

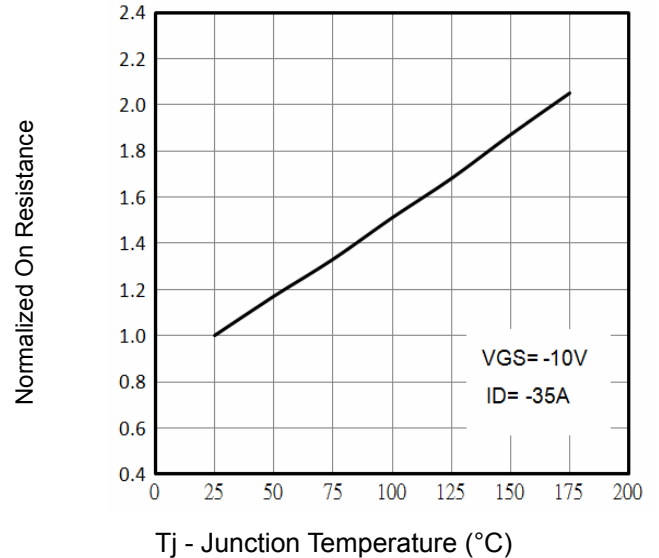


Fig4. Normalized On-Resistance Vs. Temperature

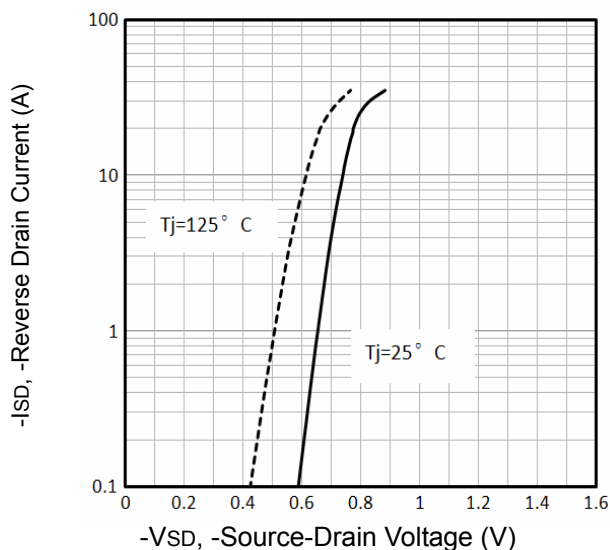


Fig5. Typical Source-Drain Diode Forward Voltage

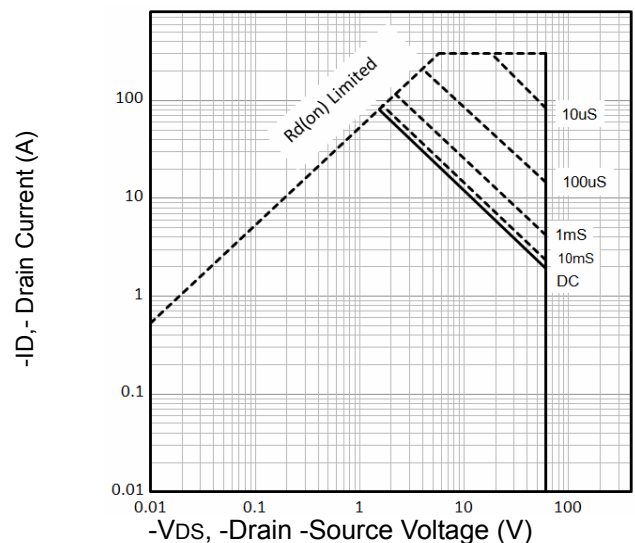
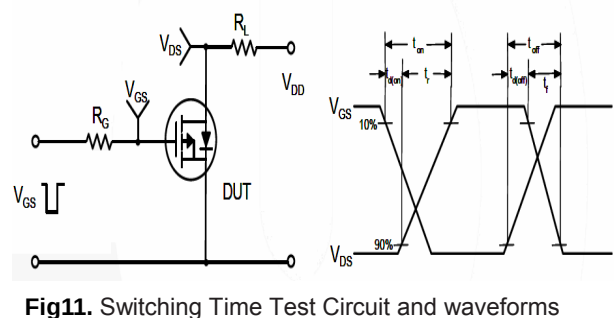
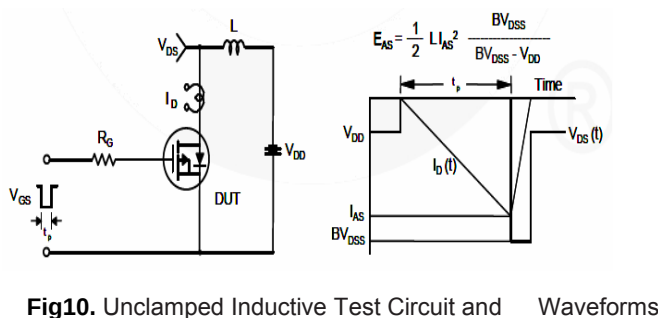
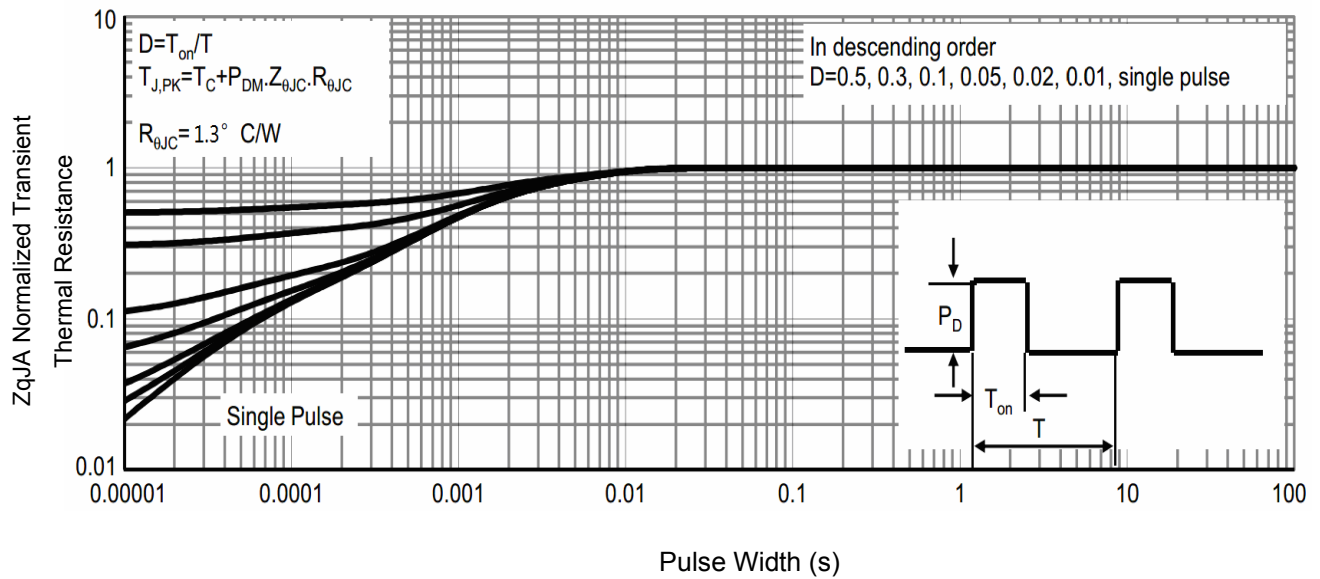
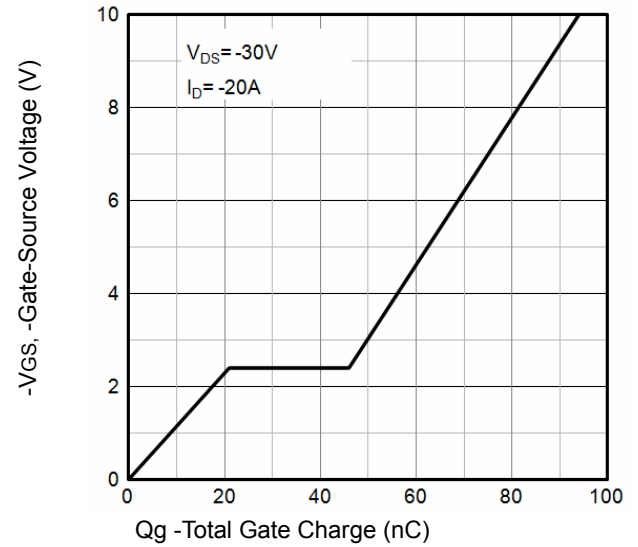
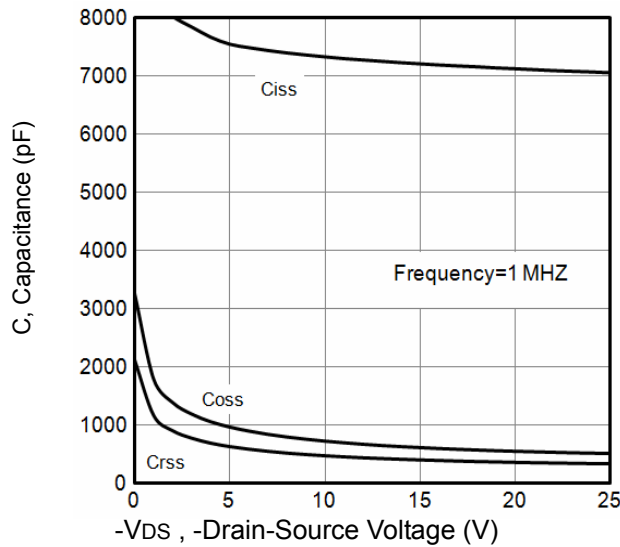
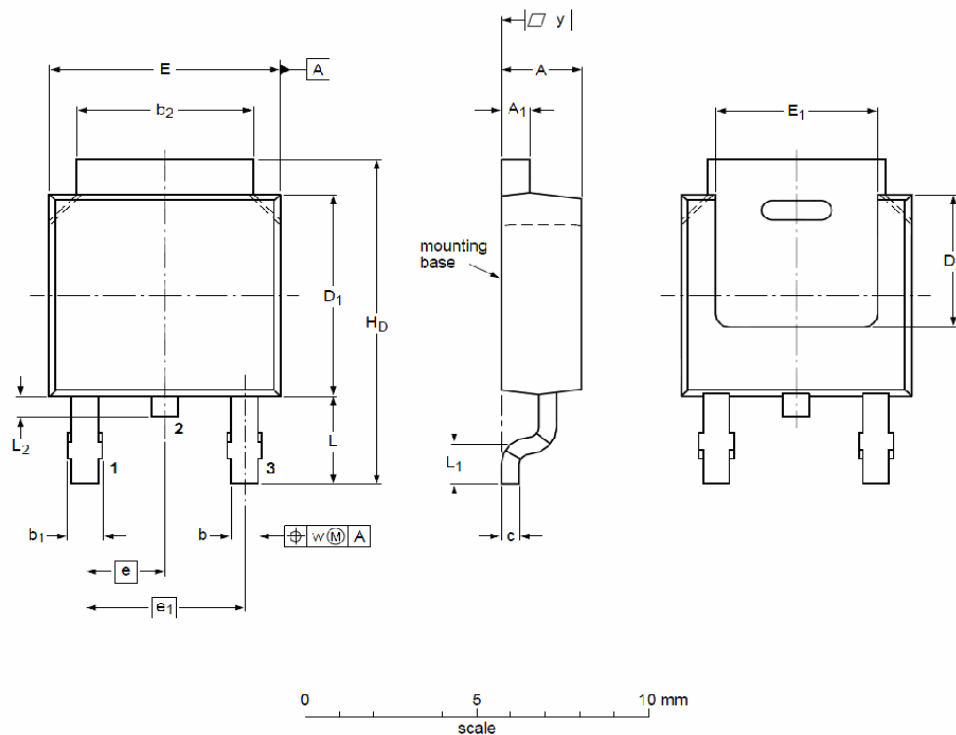


Fig6. Maximum Safe Operating Area

Typical Characteristics



TO-252 Package Outline



DIMENSIONS (unit : mm)

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	2.22	2.30	2.38	A ₁	0.46	0.58	0.93
b	0.71	0.79	0.89	b ₁	0.90	0.98	1.10
b ₂	5.00	5.30	5.46	c	0.20	0.40	0.56
D ₁	5.98	6.05	6.22	D ₂	--	4.00	--
E	6.47	6.60	6.73	E ₁	5.10	5.28	5.45
e	--	2.28	--	e ₁	--	4.57	--
H _D	9.60	10.08	10.40	L	2.75	2.95	3.05
L ₁	--	0.50	--	L ₂	0.80	0.90	1.10
w	--	0.20	--	y	0.20	--	--

Customer Service

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